



M T B F

(E I A J R C R - 9 1 0 2)

Model	TEPS65F12
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Re f e r e n c e
1	I C	M o n o l i t h i c	5	0.2200	
2		H y b r i d	0	0.0000	
3	T r a n s i s t o r s		8	0.4004	
4	D i o d e s		20	0.4315	
5	LED•Optocouplers		2	0.1400	
6	R e s i s t o r s		70	0.6559	
7	C a p a c i t o r s		56	0.5283	
8	Transformer•Choke Coil		6	0.0966	
9	C o n n e c t o r s		468	0.0754	
1 0	O t h e r s		4	0.3500	
Total Failure Rate [10 ⁻⁶ /H]				2.8981	

M T B F	[H]	345,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—